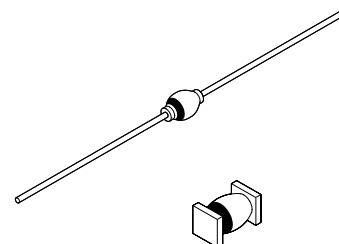


SENSITRON
SEMICONDUCTOR

JAN	SJ
JANTX	SX
JANTXV	SV

TECHNICAL DATA
DATA SHEET 158, REV D

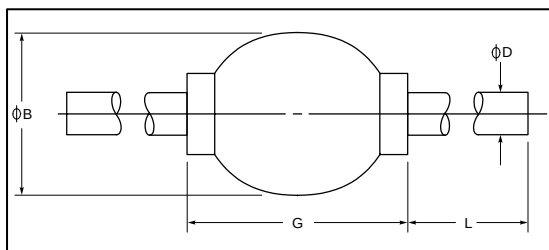
HERMETIC AXIAL / MELF LEAD RECTIFIER

DESCRIPTION: 150 VOLT, 2.5 AMP, 25 NANOSECOND RECTIFIER

MAX. RATINGS / ELECTRICAL CHARACTERISTICS All ratings are at $T_A = 25^\circ\text{C}$ unless otherwise specified.

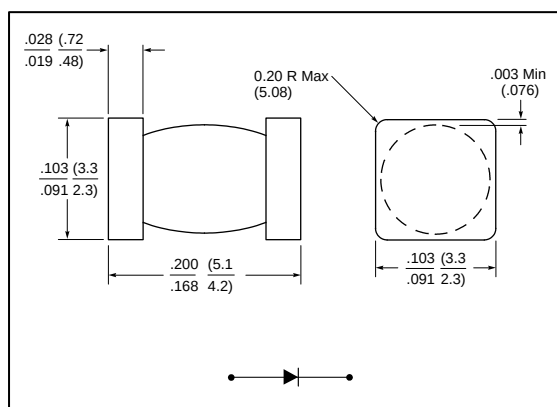
RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Inverse Voltage (PIV)	-	-	-	150	Vdc
Average DC Output Current (I_o)	$T_L = +75^\circ\text{C}$	-	-	2.5	Amps
Peak Single Cycle Surge Current (I_{fsm})	$t_p = 8.3$ ms Single Half Cycle Sine Wave, Superimposed On Rated Load	-	-	25	Amps(pk)
Operating and Storage Temp. (T_{op} & T_{stg})	-	-65	-	+175	$^\circ\text{C}$
Maximum Forward Voltage (V_f)	$I_f = 3.0\text{A}$ (300 μsec pulse, duty cycle < 2%)	-	-	.875	Volts
Maximum Instantaneous Reverse Current At Rated (PIV)	$T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	-	-	1.0 50	μAmps
Reverse Recovery Time (t_{rr})	$I_f = 0.5\text{A}$, $I_r = 0.5\text{A}$, $I_{rr} = 50\text{mA}$	-	-	25	nsec
Thermal Resistance (θ_{JL}) (Axial)	$d = 0.375"$	-	-	36	$^\circ\text{C/W}$
Thermal Resistance (θ_{JEC}) (MELF)	Junction to End Caps	-	-	20	$^\circ\text{C/W}$

MECHANICAL DIMENSIONS In Inches / (mm), min./max.



PKG. 106

ϕB	ϕD	G	L
.065 (1.65)	.027 (.69)	.125 (3.18)	.700 (17.78)
.085 (3.56)	.032 (.81)	.250 (6.35)	1.30 (33.02)



MELF-A

Note: The cathode side is marked with a dark colored band on one side of the diode body.

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